Effective on 12/08/2004.
Fees pursuant to the Consolidated Appropriations Act, 2005 (H.R. 4818).

PTO/SB/17 (10-07)
Approved for use through 06/30/2010. OMB 0651-0032
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FEE TRANSMITTAL

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Complete if Known				
Application Number	Patent#: 7,023,025B2			
Filing Date	Issued: April 4, 2006			
First Named Inventor	Johngeon SHIN			
Examiner Name	M. H. C. Tran			
Art Unit	2818			
Attorney Docket No.	1630-0135P			
one Other (please ide	ntify):			

For FY 2008		Examiner Name M. H. C. Tran				
Applicant claims small entity status. See 37 CFR 1.27		Art Unit	2818			
TOTAL AMOUNT OF PAYMENT	(\$) 100.00	Attorney Docket No.	1630-0135P	:		
METHOD OF PAYMENT (check	all that apply)					
Check Credit Card	Money Order No	ne Other (pleas	se identify):			
				Kolasch & Birch II P		
For the above-identified deposit account, the Director is hereby authorized to: (check all that apply)						
x Charge fee(s) indicated below Charge fee(s) indicated below, except for the filing fee						
fee(s) under 37 CFR 1	fee(s) or underpayments o 1.16 and 1.17	x Credit any	overpayments	į		
FEE CALCULATION				1		
1. BASIC FILING, SEARCH, AND E	XAMINATION FEES					
· F			XAMINATION FEES	1		
Application Type Fee (Small Entity \$) Fee (\$) Fee (\$	Small Entity) Fee (\$) F	Small Entity ee (\$) Fee (\$)	Fees Paid (\$)		
Utility 310			210 105			
Design 210	105 100	50	130 65			
Plant 210	105 310	155	160 80			
Reissue 310	155 510	255	620 310			
Provisional 210	105 0	0	0 0	· · · · · · · · · · · · · · · · · · ·		
2. EXCESS CLAIM FEES				Small Entity Fee (\$)		
Fee Description Each claim over 20 (including Reis	sues)			<u>Fee (\$)</u> <u>Fee (\$)</u> 50 25		
Each independent claim over 3 (including Reissues) 210 105						
Multiple dependent claims		•		370 185		
Total Claims Extra Claims	Fee (\$) Fee I	Paid (\$)	Multiple Depende			
HP = highest number of total claims paid for	x =	•	Fee (\$)	Fee Paid (\$)		
Indep. <u>Claims</u> Extra Claims	_	Paid (\$)				
- =	x =	<u> </u>				
HP = highest number of independent claims paid for, if greater than 3.						
3. APPLICATION SIZE FEE						
If the specification and drawings e						
listings under 37 CFR 1.52(e)), sheets or fraction thereof. See			man entity) for each a	dditional 50		
Total Sheets Extra Shee		idditional 50 or fraction	thereof Fee (\$)	Fee Paid (\$)		
- 100 =	/50 =	(round up to a whole n	umber) x	=		
4. OTHER FEE(S) Fees Paid (\$)						
Non-English Specification, \$130 fee (no small entity discount)						
Other (e.g., late filing surcharge): 1811 Certificate of correction 100.00						
SUBMITTED BY A A A A						
Signature (Lame)	5llfs.1	Registration No. (Attorney/Agent) 39	9,538 Telephone	(703) 205-8000		
Name (Print/Type) James T. Eller, J	ir.		Date	October 19, 2007		





Docket No.: 1630-0135P

(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Letters Patent of: Johngeon SHIN

Patent No.: 7,023,025B2

Issued: April 4, 2006

For: CRYSTAL GROWTH METHOD OF NITRIDE

SEMICONDUCTOR

REQUEST FOR CERTIFICATE OF CORRECTION PURSUANT TO 37 CFR 1.322

Attention: Certificate of Correction Branch

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

Upon reviewing the above-identified patent, Patentee noted a typographical error which should be corrected as follows.

Claim 1, as originally filed January 28, 2004, recited "a first nitride buffer layer". However, the amendment filed September 26, 2005 inadvertently omitted the word "buffer" from the limitation "a first nitride buffer layer" (i.e. the limitation currently reads "a first nitride layer"). Subsequent limitations in claim 1 refer back to "said first nitride buffer layer". Therefore, it should be clear that this omission of the word "buffer" was an obvious typographical error, and that the correction does not introduce any new matter or change the scope of the claims in any way. The present Request for Certificate of Correction is being filed to correct this obvious omission.

10/22/2007 CHGUYEN2 00000062 022448 7023025

01 FC:1811 100.00 DA

Patent No.: 7,023,025B2 Docket No.: 1630-0135P

Transmitted herewith is a proposed Certificate of Correction effecting such amendment.

Patentee respectfully solicits the granting of the requested Certificate of Correction.

Dated: October 19, 2007

Respectfully submitted,

James T. Eller, Jr.

Registration No.: 39,538

BIRCH, STEWART, KOLASCH & BIRCH, LLP

8110 Gatehouse Road

Suite 100 East P.O. Box 747

Falls Church, Virginia 22040-0747

(703) 205-8000

Attorney for Applicant

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(Also Form PTO-1050)

UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

Page	1	of	1
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PATENT NO.

7,023,025B2

APPLICATION NO.

10/765,100

ISSUE DATE

April 4, 2006

INVENTOR(S)

Johngeon SHIN

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 4, claim 1, line 3 thereof: "a first nitride layer" should read --a first nitride buffer layer--

MAILING ADDRESS OF SENDER (Please do not use customer number below):

James T. Eller, Jr. BIRCH, STEWART, KOLASCH & BIRCH, LLP 8110 Gatehouse Road

Suite 100 East P.O. Box 747

Falls Church, Virginia 22040-0747

JTE/af